

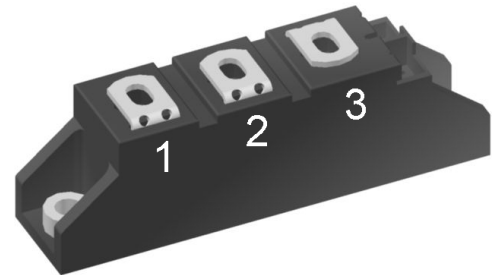
# Standard Rectifier Module

$$\begin{aligned} V_{RRM} &= 2 \times 800 \text{ V} \\ I_{FAV} &= 36 \text{ A} \\ V_F &= 1.05 \text{ V} \end{aligned}$$

Phase leg

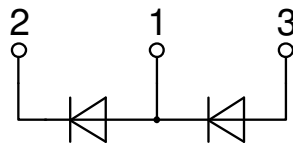
Part number

**MDD26-08N1B**



Backside: isolated

 E72873



## Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

## Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

## Package: TO-240AA

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Height: 30 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

## Terms .Conditions of usage:

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office.

Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

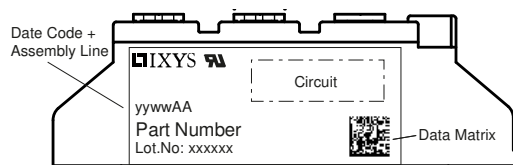
- to perform joint risk and quality assessments;

- the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
$V_{RSM}$	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}\text{C}$				900	V
$V_{RRM}$	max. repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}\text{C}$				800	V
$I_R$	reverse current	$V_R = 800\text{ V}$	$T_{VJ} = 25^{\circ}\text{C}$			100	$\mu\text{A}$
		$V_R = 800\text{ V}$	$T_{VJ} = 150^{\circ}\text{C}$			1.5	mA
$V_F$	forward voltage drop	$I_F = 40\text{ A}$	$T_{VJ} = 25^{\circ}\text{C}$			1.13	V
		$I_F = 80\text{ A}$				1.38	V
		$I_F = 40\text{ A}$	$T_{VJ} = 125^{\circ}\text{C}$			1.05	V
		$I_F = 80\text{ A}$				1.27	V
$I_{FAV}$	average forward current	$T_C = 100^{\circ}\text{C}$	$T_{VJ} = 150^{\circ}\text{C}$			36	A
$I_{F(RMS)}$	RMS forward current	180° sine				60	A
$V_{F0}$	threshold voltage	} for power loss calculation only	$T_{VJ} = 150^{\circ}\text{C}$			0.80	V
$r_F$	slope resistance					6.1	m $\Omega$
$R_{thJC}$	thermal resistance junction to case					1	K/W
$R_{thCH}$	thermal resistance case to heatsink				0.20		K/W
$P_{tot}$	total power dissipation		$T_C = 25^{\circ}\text{C}$			125	W
$I_{FSM}$	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$	$T_{VJ} = 45^{\circ}\text{C}$			650	A
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$	$V_R = 0\text{ V}$			700	A
		$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$	$T_{VJ} = 150^{\circ}\text{C}$			555	A
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$	$V_R = 0\text{ V}$			595	A
$I^2t$	value for fusing	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$	$T_{VJ} = 45^{\circ}\text{C}$			2.12	kA <sup>2</sup> s
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$	$V_R = 0\text{ V}$			2.04	kA <sup>2</sup> s
		$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$	$T_{VJ} = 150^{\circ}\text{C}$			1.54	kA <sup>2</sup> s
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$	$V_R = 0\text{ V}$			1.48	kA <sup>2</sup> s
$C_J$	junction capacitance	$V_R = 400\text{ V}; f = 1\text{ MHz}$	$T_{VJ} = 25^{\circ}\text{C}$		27		pF

Package TO-240AA				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal				200	A
$T_{VJ}$	virtual junction temperature			-40		150	°C
$T_{op}$	operation temperature			-40		125	°C
$T_{stg}$	storage temperature			-40		125	°C
Weight					76		g
$M_D$	mounting torque			2.5		4	Nm
$M_T$	terminal torque			2.5		4	Nm
$d_{Spp/App}$	creepage distance on surface   striking distance through air	terminal to terminal	13.0	9.7			mm
$d_{Spb/Apb}$		terminal to backside	16.0	16.0			mm
$V_{ISOL}$	isolation voltage	t = 1 second	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA	3600			V
		t = 1 minute		3000			V



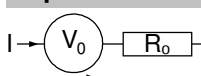
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDD26-08N1B	MDD26-08N1B	Box	36	453013

Similar Part	Package	Voltage class
MDD26-12N1B	TO-240AA	1200
MDD26-14N1B	TO-240AA	1400
MDD26-16N1B	TO-240AA	1600
MDD26-18N1B	TO-240AA	1800

## Equivalent Circuits for Simulation

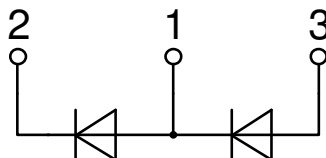
\* on die level

$T_{VJ} = 150^\circ\text{C}$



Rectifier

$V_{0\max}$	threshold voltage	0.8	V
$R_{0\max}$	slope resistance *	4.9	mΩ



## Rectifier

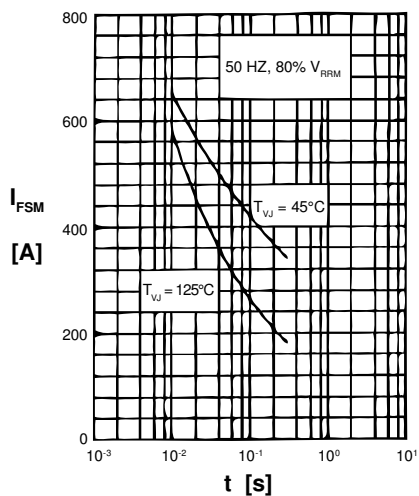


Fig. 1 Surge overload current  
 $I_{TSM}$ : Crest value,  $t$ : duration

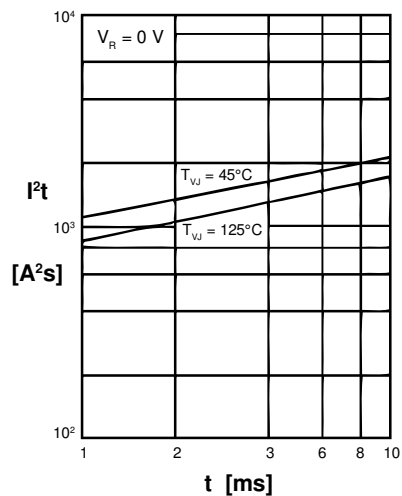


Fig. 2  $I^2t$  versus time (1-10 ms)

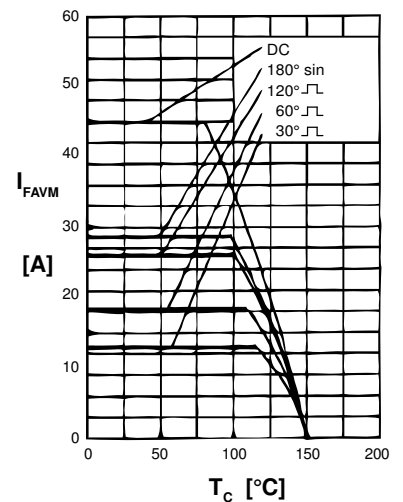


Fig. 3 Max. forward current  
at case temperature

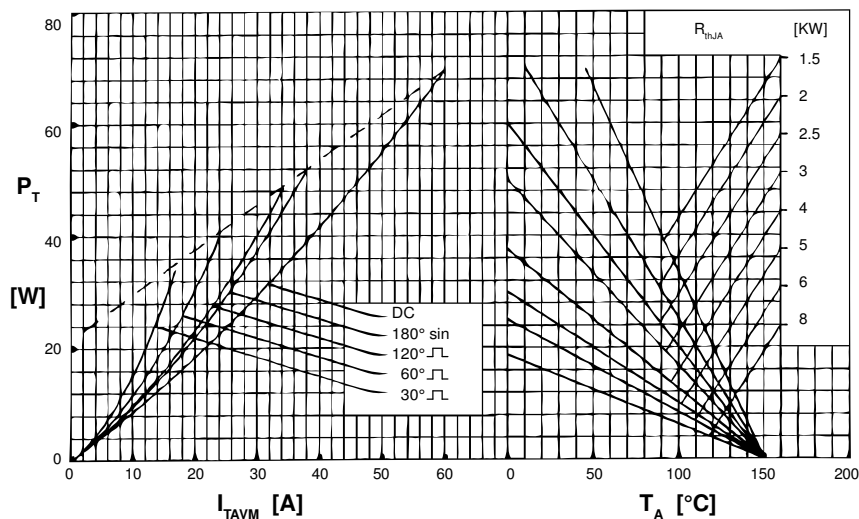


Fig. 4 Power dissipation versus onstate current & ambient temperature (per diode)

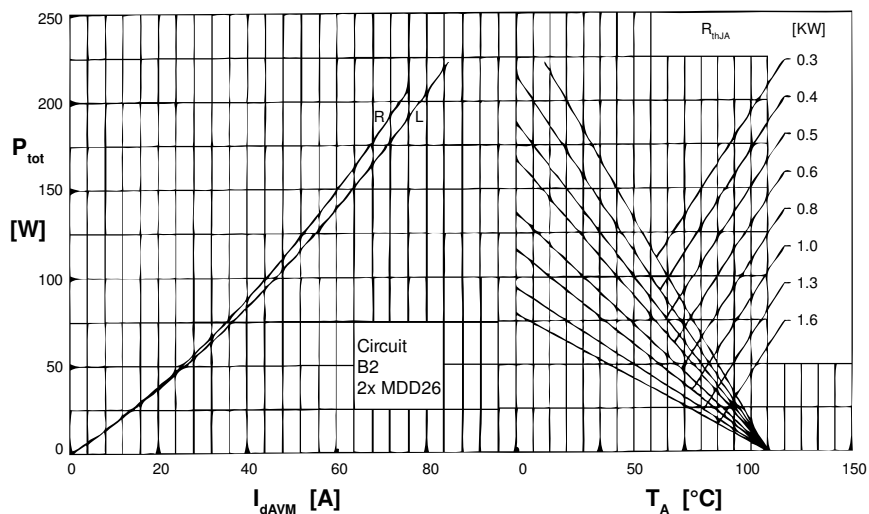


Fig. 6 Single phase rectifier bridge: Power dissipation vs. direct output current  $I^L$  and ambient temperature; R = resistive load, L = inductive load

## Rectifier

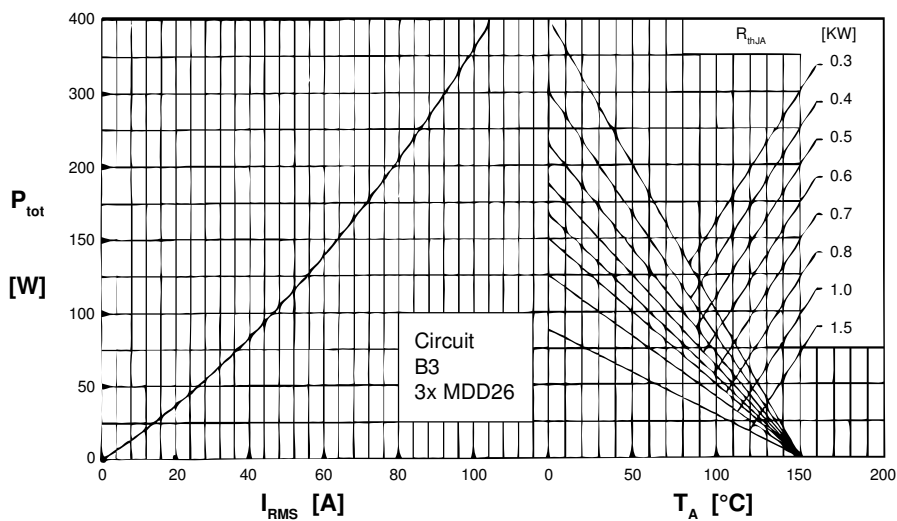


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

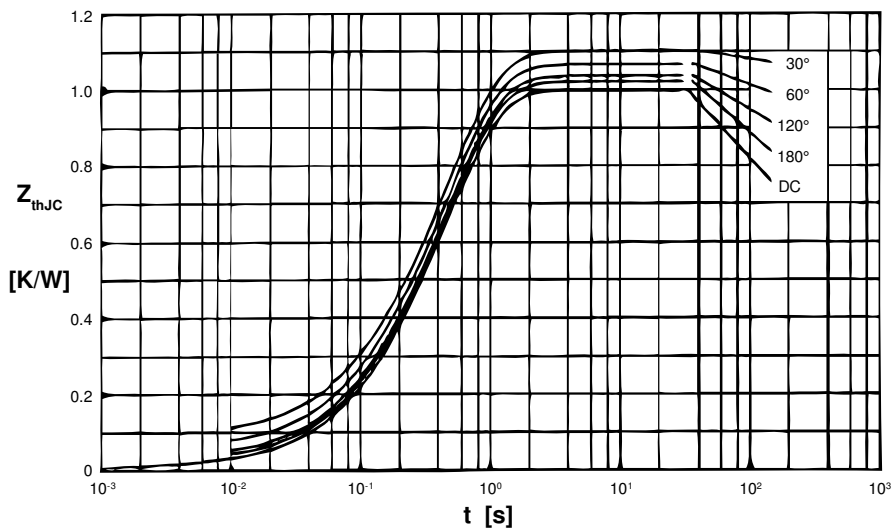


Fig. 7 Transient thermal impedance junction to case (per diode)

$R_{thJC}$  for various conduction angles d:

**d**  $R_{thJC}$  [K/W]

DC 1.00

180° 1.02

120° 1.04

60° 1.07

30° 1.10

Constants for  $Z_{thJC}$  calculation:

**i**  $R_{thi}$  [K/W]  $t_i$  [s]

1 0.01 0.0012

2 0.03 0.0950

3 0.96 0.4550

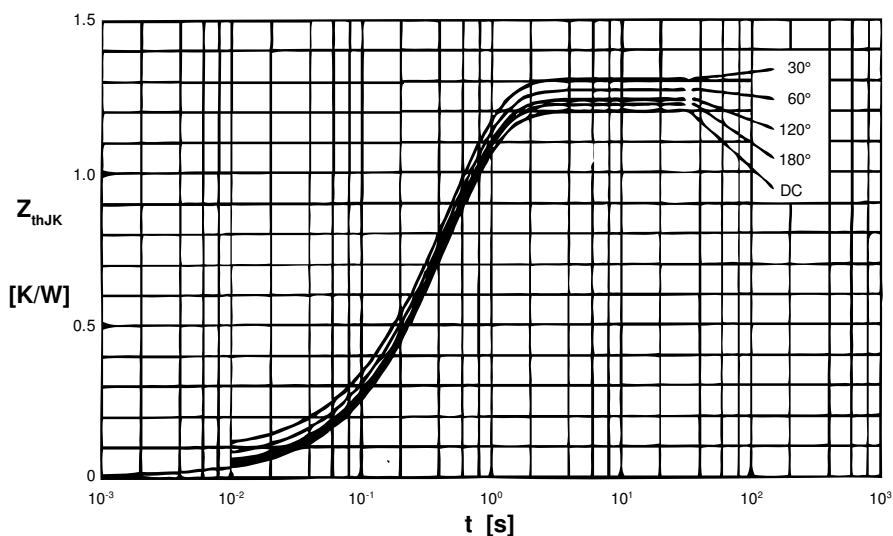


Fig. 8 Transient thermal impedance junction to heatsink (per thyristor)

$R_{thJK}$  for various conduction angles d:

**d**  $R_{thJK}$  [K/W]

DC 1.20

180° 1.22

120° 1.24

60° 1.27

30° 1.30

Constants for  $Z_{thJK}$  calculation:

**i**  $R_{thi}$  [K/W]  $t_i$  [s]

1 0.01 0.0012

2 0.03 0.0950

3 0.96 0.4550

4 0.20 0.4950